	Hit s	Search Text	DBs
15	0	implant\$6 or infus\$4) near22 (UV	US-PGPUB; USPAT; FPRS; EPO; JPO;

	Hit s	Search Text	DBs
16		or atmosphere)))) and (((organic or polymer\$4 or polyimide or polyamide or photoresist or resist) near22 (conduct\$4 or	USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit	Search Text	DBs
17		near4 (high\$3 or elevat\$4 or ris\$3)) or ((reduc\$4 or vacuum or evacuu\$5) near 3 (pressure or torr	USPAT; FPRS; EPO;
18	101	((remov\$4 or eliminat\$4 or dissipat\$\$ or rid or bounce or strip\$\$) near18 ((unbounded or mobile or loose\$3 or peripher\$5 or surface or (low near3 diffus\$5)) near8 (implant\$4 or dop\$4)) or (weak near9 (implant or dop\$4))) near29 ((temperature or heat\$3 or bak\$4 or anneal) or ((reduc\$4 near4 pressure) or vacuum or evacuu\$5))) and (((organic or polymer\$4 or polyimide or polyamide or photoresist or resist) near22 (conduct\$4 or electroconductive or semiconduct\$4 or transistor)) same (dop\$4 or implant\$4 or infus\$3))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
19	90	S18 NOT S17	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
20		((organic or polymide or photoresist) near16 (semiconduct\$4 or conduct\$4) near22 (dop\$3 or implant\$4 or infus\$4) near16 contact\$4 near9 source near12 drain near9 electrode)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
22	38	((organic or polymide) near16 (semiconduct\$4 or conduct\$4) near22 (dop\$3 or implant\$4 or infus\$4) near26 contact\$4 near20 source near16 drain)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB